# General purpose transistor (isolated transistor and diode)

# **EML20**

DTC123J

A and RB521S-30 are housed independently in a EMT6 package.

# Applications

DC / DC converter Motor driver

## Features

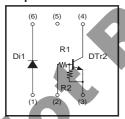
- 1) Tr : NPN digital transistor Di : Low V<sub>F</sub>
- 2) Mounting possible with EMT3 automatic mounting machines.

#### Structure

NPN Silicon epitaxial planar digital transistor Schottky barrier diode

The following characteristics apply to both Di1 and DTr2.

## Equivalent circuit

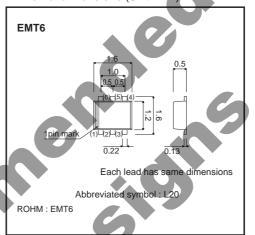


 $R_1=2.2k\Omega$ ,  $R_2=47k\Omega$ 

# Packaging specifications

Туре	EML20
Package	EMT6
Marking	L20
Code	T2R
Basic ordering unit (pieces)	8000

#### ●External dimensions (Unit : mm)



# •Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Average revtified forward current	lo	200	mA
Forward current surge peak (60Hz, 1∞)	IFSM	1	Α
Reverse voltage (DC)	VR	30	V
Junction temperature	Tj	125	°C

#### DTr2

Parameter	Symbol	Limits	Unit	
Supply voltage	Vcc	50	V	
Input voltage	VIN	12	V	
Input voltage	VIN	-5	, v	
Output ourrant	lo	100	mA	
Output current	IC (MAX.)	100	mA	
Power dissipation	Pd	120	mW *	
Junction temperature	Tj	150	°C	

<sup>\*</sup> Each terminal mounted on a recommended.

## Di1/DTr2

Parameter	Symbol	Limits	Unit
Power dissipation	Pd	150	mW *
Storage temperature	Tstg	-55 to +125	°C

<sup>\*</sup> Each terminal mounted on a recommended.

# ●Electrical characteristics (Ta=25°C)

D11						
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	VF	_	0.40	0.50	V	I=200mA
Reverse current	IR	_	4.0	30	μA	V <sub>R</sub> =10V

# DTr2

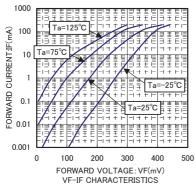
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Inner to collect to	VI(off)	+	_	0.5	V	Vcc=5V / Io=100uA
Input voltage	VI(on)	1.1	_	_	V	Vo=0.3V / Io=5mA
Output voltage	VO(on)	_	100	300	mV	lo=5mA, l≔0.25mA
Input current	11	_	_	3.6	mA	Vi=5V
Output current	IO(off)	_	_	500	nA	Vcc=50V / Vi=0V
DC current gain	Ğı	80	_	_	_	Vo=5V / Io=10mA
Transition frequency *	f⊤	-	250	_	MHz	Vce=10V / Ie= -5mA, f=100MHz
Input resistance	R <sub>1</sub>	1.54	2.2	2.86	kΩ	_
Resistance ratio	R2/R1	17	21	26	_	-

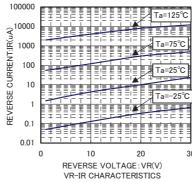
<sup>\*</sup> Characteristics of built-in transistor.

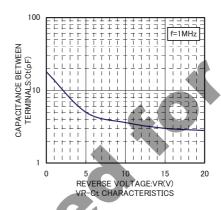


#### •Electrical characteristic curves

Di1







DTr2

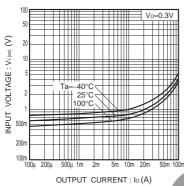


Fig.1 Input voltage vs. output current (ON characteristics)

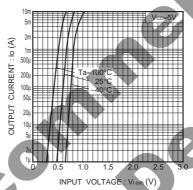


Fig.2 Output current vs. input voltage (OFF characteristics)

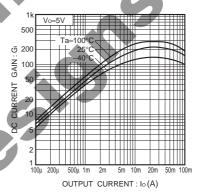


Fig.3 DC current gain vs. output current

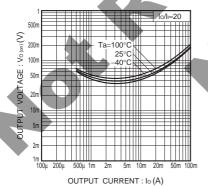


Fig.4 Output voltage vs. output current

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